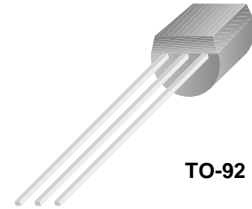


# BF494

## NPN RF Transistor



TO-92

1. Collector 2. Emitter 3. Base

### Absolute Maximum Ratings \* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Unit
$V_{CEO}$	Collector-Emitter Voltage	20	V
$V_{CBO}$	Collector-Base Voltage	30	V
$V_{EBO}$	Emitter-Base Voltage	5.0	V
$I_C$	Collector Current - Continuous	30	mA
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range	- 55 ~ 150	$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

**NOTES:**

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

### Thermal Characteristics

Symbol	Parameter	Value	Unit
$P_D$	Total Device Dissipation, by $R_{\theta JA}$ Derate above $25^\circ\text{C}$	350	mW
		2.8	mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to case	125	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	$^\circ\text{C}/\text{W}$

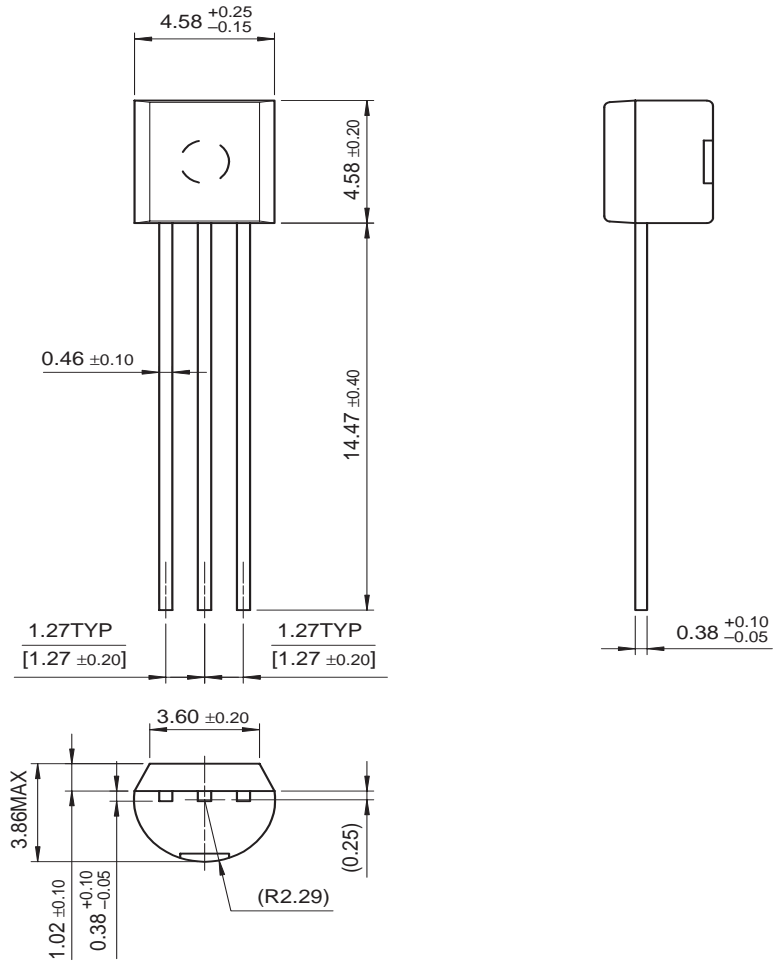
### Electrical Characteristics\* $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max.	Units
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1.0\text{mA}, I_B = 0$	20		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10\mu\text{A}, I_E = 0$	30		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10\mu\text{A}, I_C = 0$	5.0		V
$I_{CES}$	Collector-Emitter Sustaining Current	$V_{CE} = 40\text{V}, V_{EB} = 0\text{V}$		10	nA
$h_{FE}$	DC Current Gain	$V_{CE} = 10\text{V}, I_C = 1\text{mA}$	67	222	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 5\text{mA}$		0.2	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 5\text{mA}$		0.92	V
$V_{BE(ON)}$	Base-Emitter On Voltage	$V_{CE} = 10\text{V}, I_C = 10\text{mA}$	650	740	mV

\* DC Item are tested by Pulse Test: Pulse Width $\leq$ 300us, Duty Cycle $\leq$ 2%

# Package Dimensions

## TO-92



Dimensions in Millimeters

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FAST®	MicroFET™	QS™	TinyBuck™	
FASTr™	MicroPak™	QT Optoelectronics™	TinyPWM™	
FPST™	MICROWIRE™	Quiet Series™	TinyPower™	
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Programmable Active Droop™				

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**Definition of Terms**

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